

Peak pulse voltage ($T_j=25$; non-repetitive, off-state; FIG.8)	V_{pp}	4	kV
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ELECTRICAL CHARACTERISTICS (unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	$V_D=12V$ $R_L=33$	- -	MAX.	10	mA
V_{GT}		- -	MAX.	1	V
V_{GD}	$V_D=V_{DRM}$ $T=125$ $R_L=3.3k$	- -	MIN.	0.2	V
L	$I_G=1.2I_{GT}$				
				30	
H	I_T				
dV/dt	$V_D=670V$ Gate Open $T_j=125$		MIN.	300	V/s
$(dI/dt)_c$	$(dV/dt)_c=10^9$ $V_j=125$		MIN.	1.5	A/ms

FIG.1: Maximum power dissipation versus RMS on-state current

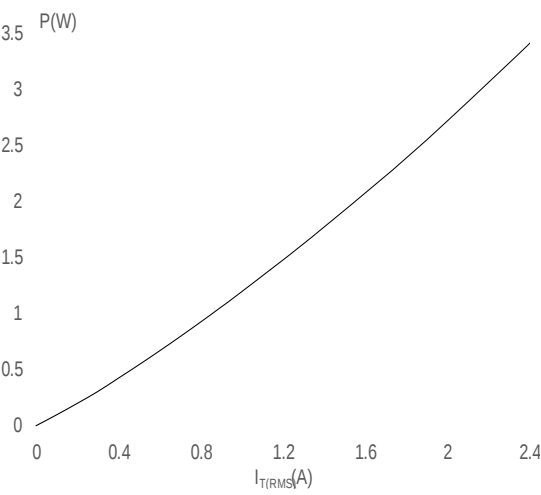


FIG.3: RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness: P IXOO F\FOH

FIG.2: RMS on-state current versus case temperature

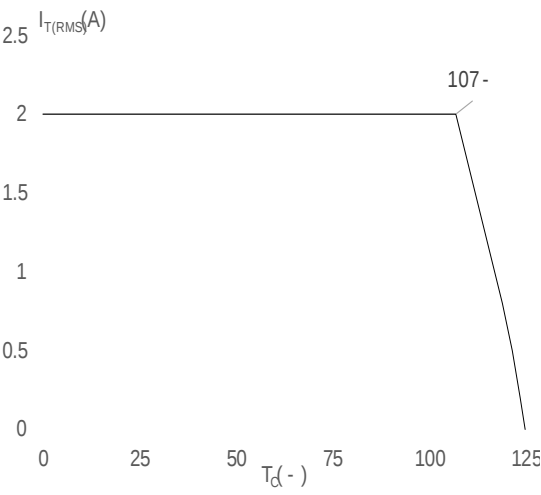
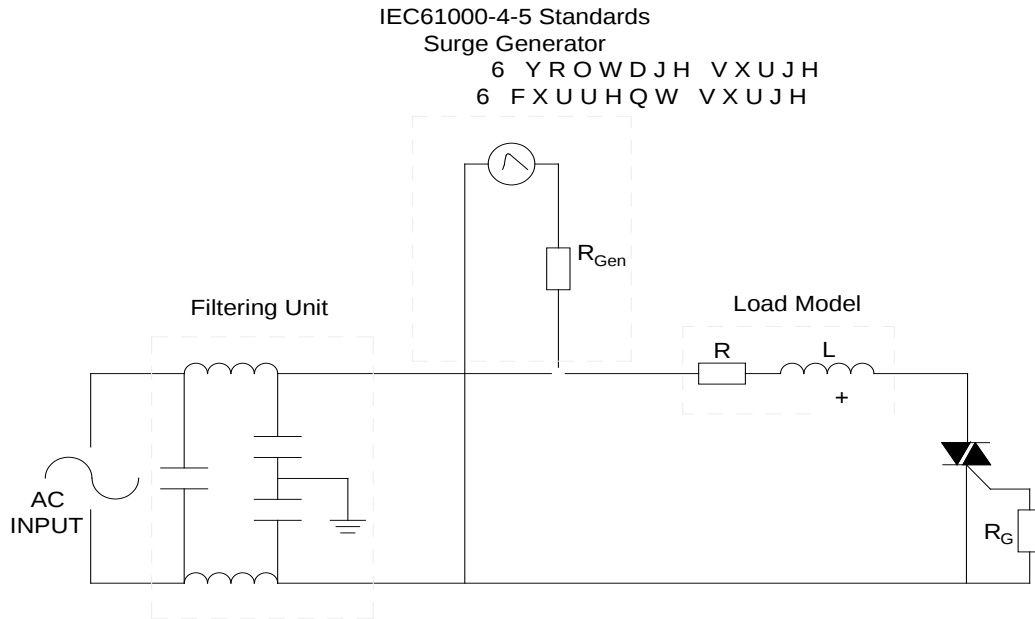


FIG.4: Surge peak on-state current versus number of cycles

JST02K-1000SW

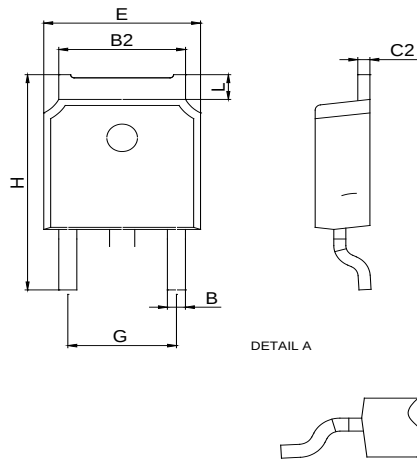
FIG.8 ÖTest circuit for inductive and resistive loads to IEC-61000-4-5 standards



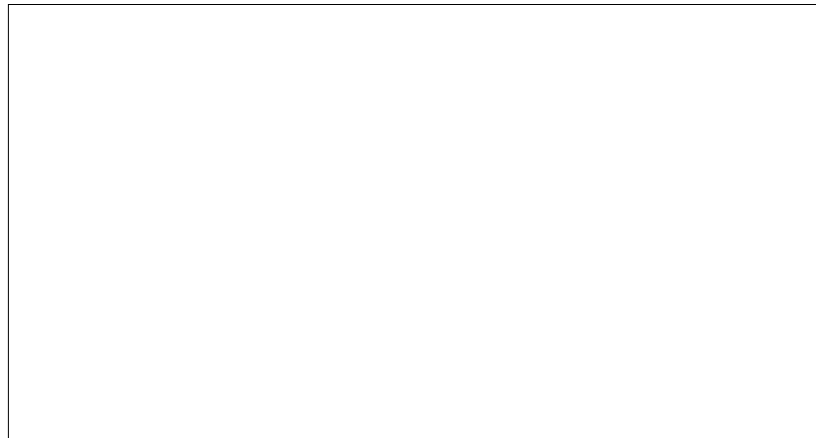
ORDERING INFORMATION

Order code	Voltage V _{DRM} /V _{RRM} (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		H- I- J			

PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.15	0		0.006
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1						
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
G1	2.18		2.38	0.086		0.094
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065



DELIVERY MODE

